	Type	Hits	Search Text	DBs
1	BRS	3525	(Jian Hsung).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	0	(Jian-Hsung).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BRS	163	((Jian Hsung)and lee).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BRS	47	(((Jian Hsung)and lee).in.) and esd	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BRS	26	(((Jian Hsung)and lee).in.) and esd and 361/$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BRS	0	esd and (switch$3 same predetermine same level)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	BRS	1	esd and (predetermine same level)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
8	BRS	793	esd and (pad same internal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
9	BRS	257	esd and (pad same internal same (mos nmos pmos))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
10	BRS	138	esd and (pad same internal same (mos nmos pmos)) and (voltage same level)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
11	BRS	55	esd and (pad same internal) and (voltage same level same detect$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
12	BRS	0	esd and (pad same internal) and (multivoltage same voltage same level same detect$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
13	BRS	0	esd and (pad same internal) and (multivoltage same detect$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
14	BRS	0	esd and (multivoltage same detect$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
15	BRS	2	esd and multivoltage and detect$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
16	BRS	89	esd and (diode adj3 string)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
17	BRS	22	(esd and (diode adj3 string)) and detect$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB